

#### **PRODUCTION DATASHEET**

# **DESCRIPTION**

LX7169 is a step-down PWM Switching regulator IC with integrated high side P-Channel and low side N-Channel MOSFETs. The IC operates using a hysteretic control topology with a full load operating frequency of 3MHz. This switching frequency allows for small output filter components while maintaining excellent dynamic load response.

The operational input voltage range of LX7169 is from 3V to 5.5V. The SYNC pin is tied low when not in use. A clock signal to this pin will synchronize the converter to an external source.

In the shutdown mode, the IC's current consumption is reduced to less than 1mA and the output capacitor is discharged.

Other features of the part are:

- a) Cycle-by-cycle current limit followed by HICCUP mode which reduces the overall power dissipation of the internal MOSFETs
- b) Thermal protection and internal digital soft start.

The LX7169 also provides a Power Good function. The LX7169 is available in a 12L 3mm x 3.5mm DFN package.

## **KEY FEATURES**

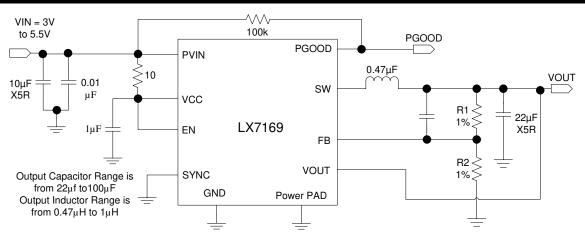
- 3A Step-down Regulator
- Operational Input Supply Voltage Range: 3V-5.5V
- Integrated PMOS and NMOS
- Load Current from zero to 3A
- 3MHz Switching Frequency
- Input UVLO Protection
- Enable Pin
- Power Good
- Internal Soft-start
- Cycle-by-Cycle Over Current Protection
- Hiccup Mode Operation Under OCP
- RoHS Compliant for Pb Free

## **APPLICATIONS**

- HDD
- Set-Top Box
- LCD TV's
- Notebook/Netbook
- Routers
- Video Cards
- PC Peripherals
- PoE Powered Devices

IMPORTANT: For the most current data, consult MICROSEMI's website: <a href="http://www.microsemi.com">http://www.microsemi.com</a>

## PRODUCT HIGHLIGHT



	PACKAGE ORDER INFO	THERMAL DATA		
T. (9C)	12L DFN (3.0 x 3.5 mm)	$\theta_{\rm JA} = 36^{\circ}{ m C/W}$		
T <sub>A</sub> (°C)	RoHS Compliant / Pb-free	THERMAL RESISTANCE-JUNCTION TO AMBIENT		
		Junction Temperature Calculation: $T_J = T_A + (P_D \times \theta_{JA})$ . The $\theta_{JA}$ numbers are guidelines for the thermal performance of the		
-10 to +85	LX7169CLD			

# Microsemi

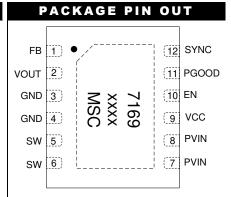


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0.3V to 7V
0.3V to 7V
2V to 7V
0°C to 150°C
5°C to 150°C
260°C (+0,-5)

Notes: Exceeding these ratings could cause damage to the device. All voltages are with respect to GND.

Currents are positive into, negative out of specified terminal. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" are not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.



## LD PACKAGE

(Top View)
Exposed Pad = GND
xxxx = Date/Lot Code
RoHS / Pb-free 100% Matte Tin Lead
Finish

		ions apply over the operating ambient temperature of - $^{\circ}$ /CC = PVIN = 5V. Typical parameter refers to T $_{\rm J}$ =25 $^{\circ}$ C		≨ 85°C ex	cept where	)
Parameters	Symbol	Test Conditions/Comments	Min	Тур	Max	Units
Recommended Operatin	g Range		•	W.	·!	и.
VCC, PVIN			3		5.5	V
Operating Current				•		•
Input Current	lα	I <sub>LOAD</sub> = 0		12		mA
Input Current at Shut Down	I <sub>IN</sub>	EN = GND		0.001	1	mA
VCC Input UVLO				•		•
Under Voltage Lockout	VCC	VCC rising		2.4	2.8	V
UVLO Hysteresis				230		mV
Feedback	•		•	•	•	•
Feedback Voltage Internal Reference	$V_{REF}$	T <sub>A</sub> = 25°C	0.792	0.800	0.808	V
		Temperature range	0.788		0.812	V
FB Pin Input Current	I <sub>FB</sub>				10	nA
Line Regulation		V <sub>IN</sub> from 3V to 5.5V		0.30		%
Load Regulation		I <sub>LOAD</sub> = 0.5 to 3A		-0.10		%/A
Vout Voltage Positioning	$V_{REG}$	Vout = 1.2V, Hysteretic Mode		1%		
Transient Response		Load from 0.1 to 1.5 amps, $T_R = T_F = 100$ ns, $V_{OUT} = 1.2 V$ $C_{OUT} = 44 \mu F$		+/-40		mV
FB UVLO						
FB UVLO Threshold	V <sub>FBULVO</sub>			70%		V <sub>REF</sub>

**ELECTRICAL CHARACTERISTICS** 



		FRODUCTION	DATASI	1661		
		ECTRICAL CHARACTERISTICS		0500		
otherwise noted with the following tes	ving specificati st conditions: \	ions apply over the operating ambient temperature of -10 $^{\prime}$ /CC = PVIN = 5V. Typical parameter refers to T $_{\rm J}$ =25°C	°C≤ I <sub>A</sub> ≤	₃ 85°C exc	ept where	
Parameters	Symbol	Test Conditions/Comments	Min	Тур	Max	Units
OUTPUT DEVICE		•	•	•	•	•
R <sub>DSON</sub> of High Side	R <sub>DSON_H</sub>			60	90	mΩ
R <sub>DSON</sub> of Low Side	R <sub>DSON_L</sub>			40	60	mΩ
Current Limit	ΙL		3.75	4.5	5.5	Α
Thermal Shut Down Threshold	T <sub>SH</sub>			150		°C
Hysteresis	T <sub>H</sub>			20		°C
PVIN OVP			•			
Rising Threshold	OVPR			6.5		V
Falling Threshold	OVP <sub>F</sub>		5.5	6.3		V
OSCILLATOR FREQUE	ENCY	•	•	•	•	•
Switching Frequency	F	In Constant Frequency Hysteretic Mode	2.6	3	3.4	MHz
SOFT START						
Soft Start Time	T <sub>SS</sub>	From EN high to PGOOD high.		500		μs
Hiccup Time	T <sub>HICCUP</sub>	FB = 0.2V		1.5		ms
SYNC			•			
Input High	M <sub>VIH</sub>		1			V
Input Low	M <sub>VIL</sub>				0.4	V
EN INPUT		•	•	•	•	•
Input High	EN <sub>VIH</sub>		1			V
Input Low	EN <sub>VIL</sub>				0.4	٧
Hysteresis	EN <sub>H</sub>			0.1		٧
Input Bias	EΝ <sub>II</sub>			0.01	1	μΑ
POWER-GOOD		•	•	•	•	•
Power-good Transition High Threshold	V <sub>PG</sub>	V <sub>FB</sub> rising, In percentage of output voltage set- point. During startup, the PGOOD will not go high until the soft start cycle has finished.		83		%
Hysteresis	$V_{PGHY}$	Either V <sub>FB</sub> rising or falling		40		mV
Power-good Internal FET R <sub>DSON</sub>	PG <sub>RDSON</sub>	VCC=5V		100	300	ohm
PGOOD FET Leakage Current				0.01	1	μΑ
Pgood Internal Glitch Filter				5		μSec
Output Discharge						
Internal Discharge Resistor			80	200	1400	ohm



FUNCTIONAL PIN DESCRIPTION					
Name	Pin#	Description			
FB	1	Voltage feedback pin. Connect to the output terminal through a resistor divider network to set the output voltage of the regulator to the desired value.			
VOUT	2	Attached to V <sub>OUT</sub> .			
GND	3,4	Ground pin for the power stage.			
SW	5,6	Switch-node pin. Connect the output inductor between this pin and output capacitor. When the chip is DISABLED, the internal discharge resistor will be enabled to discharge the output capacitance. The current will flow into this pin.			
PVIN	7,8	Input voltage terminal of the regulator. A minimum of $10\mu F$ , X5R type ceramic capacitor must be connected as close as possible from this pin to PGND plane to insure proper operation.			
VCC	9	Analog input voltage terminal. Connect this pin to VIN with a 10ohm resistor and connect a $1\mu F$ ceramic capacitor from VCC to GND.			
EN	10	Pull this PIN higher than 1V will enable the CHIP. When pulled low, the IC will turn off and the Internal discharge FETwill turn on to discharge the output capacitor through the SW pin.			
PGOOD	11	Power-good pin. This is an open-drain output and should be connected to a voltage rail with an external pull-up resistor. During the power on, this pin switches from Low to Hi state when FB voltage reaches above the power good threshold and the internal soft start has finished its operation. It will be pulled low when the FB falls below the power good threshold minus the hysteresis It will turn back on when the pull FB rises above the threshold.			
SYNC	12	This pin should be tied to ground when not in use. When a clock is connected. The IC will be in synchronous mode and switching frequency is synchronized to external CLOCK.			
Power PAD		Ground pin for the power stage and analog circuit. For good thermal connection, this PAD must be connected using VIAs to the GND plane and to the LAND pattern of the IC.			



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# FUNCTIONAL BLOCK DIAGRAM

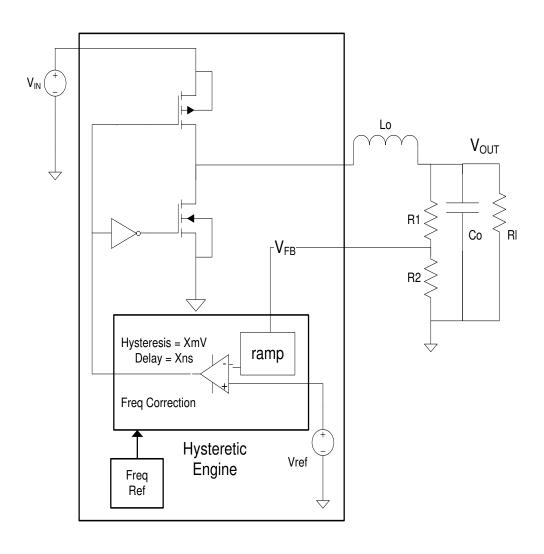


Figure. 1. Functional Block Diagram.



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# **OPERATION THEORY**

# **Basic Operation**

The operation of the controller consists of comparing the  $V_{fb}$  voltage to an internal reference. When the  $V_{fb}$  voltage is lower than the  $V_{ref}$ , the upper switch turns on. When the  $V_{fb}$  voltage is higher than  $V_{ref}$ , the upper switch turns off and the lower switch turns on. An internal ramp is used to stabilize the switching frequency and keep the  $V_{fb}$  immune to the output capacitor, Co, value or parasitic components (i.e. esr, esl). In addition, a frequency control loop ensures the switching frequency is constant under continuous conduction mode of operation.

# Setting of the Output Voltage

The values of R1 and R2 are chosen so according to the following equations:

$$V_{OUT} = \left(\frac{R_1}{R_2} + 1\right) V_{ref}$$

# Startup

The Reference is ramped up from zero voltage to 0.8V in  $500\mu S$ . During this time, the PGOOD is pulled low. When the reference reaches 0.8V, signaling the end of the soft start cycle, the PGOOD pin will go high within  $5\mu S$ .

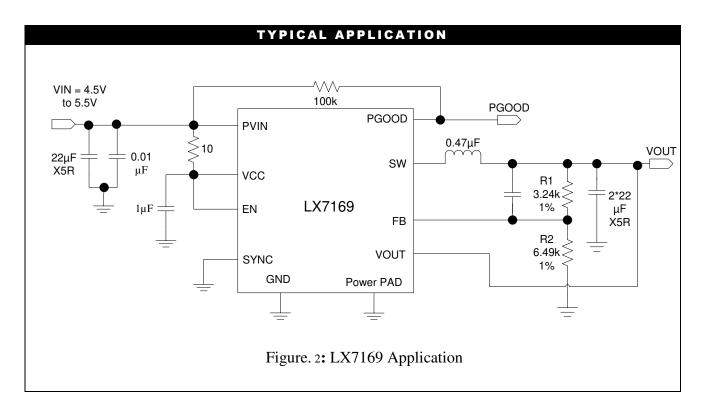
# **Over Current Protection**

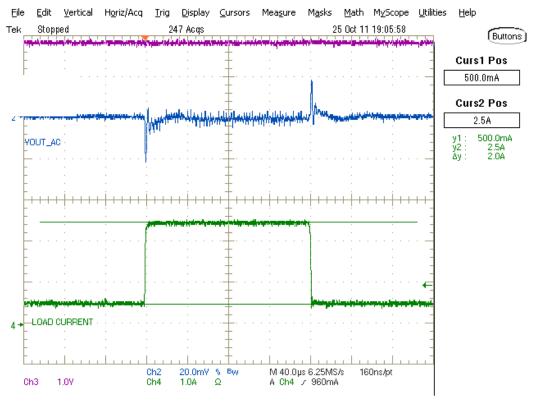
The IC has the ability to protect against all types of short circuit protection. It has cycle by cycle short protection that turns off the upper mosfet and ends the cycle when the current exceeds the OCP threshold, when this occurs, the off time is at least 200ns before the upper fet is turned on again After startup, if the FB pin drops below the Feedback UVLO threshold, the chip will go into a hiccup mode of operation. This helps to protect against a crowbar short circuit. The FB UVLO Alarm is not active during startup.

# Hiccup Mode of Operation

Hiccup mode of operation will protect the IC during a short of the output. After startup, it will be triggered when the FB UVLO is exceeded







2A Dynamic response (0.47μH, 2x22μF)



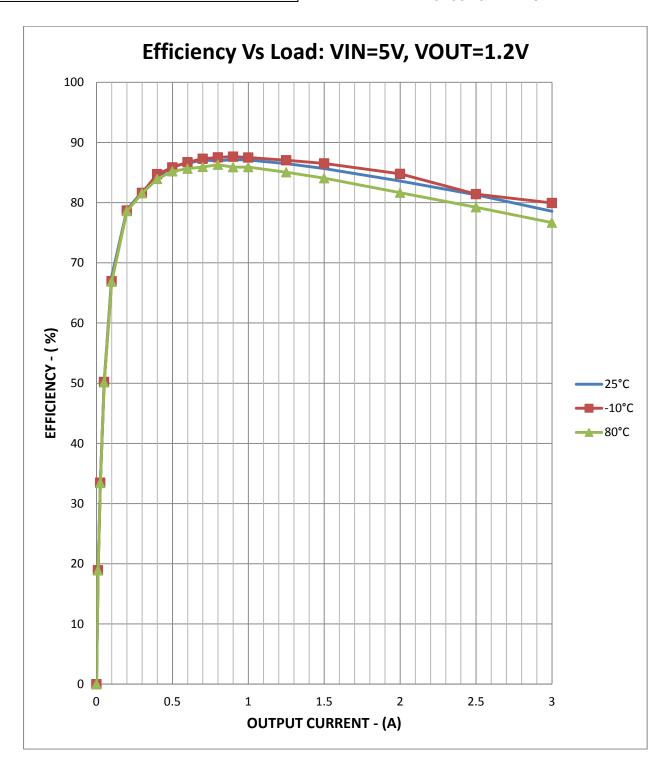


Figure 3. LX7169 Efficiency (Inductor part number: IHLP1616ABER47M01)

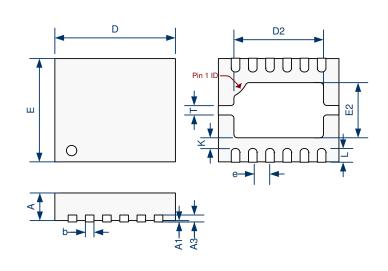


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# PACKAGE DIMENSIONS

LD

12 Pin Plastic DFN 3x3.5 mm Dual Exposed Pad



	MILLIMETERS		INCHES		
Dim	MIN	MAX	MIN	MAX	
Α	0.70	0.80	0.027	0.031	
A1	0	0.05	0	0.002	
A3	0.20	REF	0.008 REF		
b	0.18	0.30	0.007	0.012	
D	3.50	BSC	0.138 BSC		
D2	2.45	2.70	0.096	0.106	
е	0.50	BSC	0.019 BSC		
Е	3.00	BSC	0.118 BSC		
E2	1.45	1.70	0.057	0.067	
L	0.35	0.55	0.014	0.022	
Т	0.20	0.30	0.008	0.012	

## Note:

- Dimensions do not include mold flash or protrusions; these shall not exceed 0.155mm(.006") on any side. Lead dimension shall not include solder coverage.
- Dimensions are in mm, inches are for reference only.

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